## NSN 5962-01-535-6032

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View Online at https://aerobasegroup.com/nsn/5962-01-535-6032 **Body Length:** 0.960 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.130 inches and 0.185 inches **Maximum Power Dissipation Rating:** 950.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **End Application:** Plus 4 dgu **Features Provided:** Electrostatic sensitive and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Current Rating Per Characteristic:** 185.00 milliamperes reverse current, dc absolute **Product Name:** Microcircuit assembly sin-low **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.0 volts power source and -1.5 volts input and 5.5 volts input **Time Rating Per Chacteristic:** 90.00 nanoseconds access **Memory Device Type:** Prom **Memory Capacity:** 2k x 4 **Terminal Type And Quantity:** 18 printed circuit Shelf Life: N/a **Unit Of Measure:** 

**Demilitarization:** 

Yes - demil/mli

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